









SN65C3221, SN75C3221 SLLS351F - APRIL 2002 - REVISED JULY 2021

3-V to 5.5-V Single-Channel RS-232 Compatible Line Driver and Receiver

1 Features

- Operate with 3-V to 5.5-V V_{CC} supply
- Operate up to 1 Mbit/s
- Low standby current : 1 µA typical
- External capacitors: 4 x 0.1 µF
- Accepts 5-V logic input with 3.3-V supply
- RS-232 bus-pin ESD protection exceeds ±15 kV using human-body model (HBM)
- Auto-powerdown feature automatically disables drivers for power savings

2 Applications

- **Industrial PCs**
- Wired networking
- Data center and enterprise computing
- Battery-powered systems
- **PDAs**
- **Notebooks**
- Laptops
- Palmtop PCs
- Hand-held equipment

3 Description

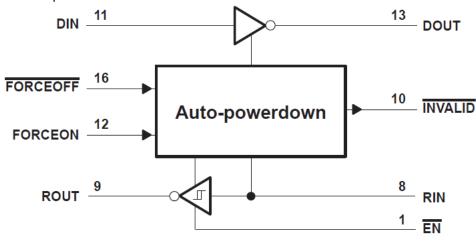
The SN65C3221 and SN75C3221 consist of one line driver, one line receiver, and a dual chargepump circuit with ±15-kV ESD protection pin to pin (serial-port connection pins, including GND). These devices provide the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. These devices operate at data signaling rates up to 1 Mbit/s and a driver output slew rate of 24 V/µs to 150 V/µs.

Flexible control options for power management are available when the serial port is inactive. The autopowerdown feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the devices do not sense a valid RS-232 signal on the receiver input, the driver output is disabled. If FORCEOFF is set low and EN is high, both the driver and receiver are shut off, and the supply current is reduced to 1 µA. Disconnecting the serial port or turning off the peripheral drivers causes the auto-powerdown condition to occur. Autopowerdown can be disabled when FORCEON and FORCEOFF are high. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to the receiver input. The INVALID output notifies the user if an RS-232 signal is present at the receiver input. INVALID is high (valid data) if the receiver input voltage is greater than 2.7 V or less than -2.7 V, or has been between -0.3 V and 0.3 V for less than 30 µs. INVALID is low (invalid data) if the receiver input voltage is between -0.3 V and 0.3 V for more than 30 µs. Refer to Figure 7-5 for receiver input

Device Information

| PART NUMBER | PACKAGE ⁽¹⁾ | BODY SIZE (NOM) | | |
|-------------|------------------------|-------------------|--|--|
| SNx5C3221 | SSOP (DB) 16 | 6.20 mm x 5.30 mm | | |
| SNX5C3221 | TSSOP (PW) 16 | 10.3 mm x 7.50 mm | | |

For all available packages, see the orderable addendum at the end of the data sheet.



Logic Diagram (Positive Logic)



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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| C | hanges from Revision E (October 2004) to Revision F (July 2021) | Page |
|---|--|-----------------|
| • | Changed the Applications list | 1 |
| | Deleted the Oderaing Information table | |
| • | Added the Device Information table | 1 |
| • | Removed the thermal parameters from Absolute Maximum Ratings table and moved them to Thermal | |
| | Information table | 4 |
| • | Added ESD Ratings table. Moved the driver and receiver ESD specifications to this table | 4 |
| • | Changed the thermal parameters for PW package of SN65C3221 and DB package of SN75C3221. Add | ded |
| | additional thermal parameters for both the packages in the <i>Thermal Information</i> table | 5 |
| • | Added the Detailed Description section | <mark>11</mark> |
| | | |



5 Pin Configuration and Functions

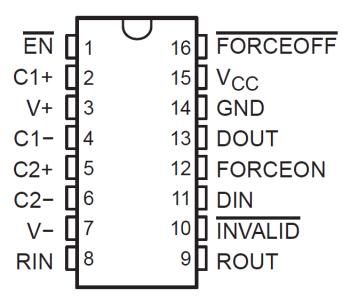


Figure 5-1. DB or PW Package Top View

Table 5-1. Pin Functions

| P | IN | | DESCRIPTION |
|-----------------|----|-----|---|
| NAME NO. I/O | | I/O | |
| C1+ | 2 | _ | Positive terminals of the voltage-doubler charge-pump capacitors |
| C2+ | 5 | | |
| C1- | 4 | _ | Negative terminals of the voltage-doubler charge-pump capacitors |
| C2- | 6 | | |
| DIN | 11 | 1 | Driver input |
| DOUT | 13 | 0 | RS-232 driver output |
| EN | 1 | I | Low input enables receiver ROUT output. High input sets ROUT to high impedance. |
| FORCEOFF | 16 | I | Automatic power-down control input |
| FORCEON | 12 | ı | Automatic power-down control input |
| GND | 14 | _ | Ground |
| INVALID | 10 | 0 | Invalid output pin. Output low when all RIN inputs are unpowered. |
| RIN | 8 | I | RS-232 receiver input |
| ROUT | 9 | 0 | Receiver output |
| V _{CC} | 15 | _ | 3-V to 5.5-V supply voltage |
| V+ | 3 | 0 | 5.5-V supply generated by the charge pump |
| V– | 7 | 0 | -5.5-V supply generated by the charge pump |



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

| | | | MIN | MAX | UNIT |
|------------------|--|--------------------------------|-------|-----------------------|------|
| V _{CC} | Supply voltage range | | -0.3 | 6 | V |
| V+ | Positive output supply voltage | ge range ⁽²⁾ | -0.3 | 7 | V |
| V- | Negative output supply volta | ge range ⁽²⁾ | -7 | 0.3 | V |
| V+ – V – | Supply voltage difference ⁽²⁾ | | | 13 | V |
| \/ | Input voltage range | Driver (FORCEOFF, FORCEON, EN) | -0.3 | 6 | V |
| V _I | | Receiver | -25 | 25 | V |
| \/ | | Driver | -13.2 | 13.2 | |
| Vo | Output voltage range | Receiver (INVALID) | -0.3 | V _{CC} + 0.3 | V |
| TJ | Operating virtual junction temperature | | | 150 | °C |
| T _{stg} | Storage temperature | | -65 | 150 | °C |

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Section 6.3 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

| | | | | VALUE | UNIT |
|---------|---|--|----------------|-------|------|
| | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ¹ | RIN and DOUT Pins | ±15000 | | |
| V (ESD) | Electrostatic discharge | | All other pins | ±3000 | V |
| | | Charged-device model (CDM), per JEDEC specification JESD22-C101 ² | All pins | ±1500 | |

6.3 Recommended Operating Conditions⁽¹⁾

(see Figure 9-1)

| | | | | MIN | NOM | MAX | UNIT |
|----------|---|----------------------------|-------------------------|-----|-----|-----|------|
| | Supply voltage | V | | | | 3.6 | V |
| | Supply voltage | | | 4.5 | 5 | 5.5 | V |
| V | Driver and control high-level input voltage | DIN, FORCEOFF, FORCEON, EN | V _{CC} = 3.3 V | 2 | | | V |
| V_{IH} | | DIN, FORCEOFF, FORCEON, EN | V _{CC} = 5 V | 2.4 | | | V |
| V_{IL} | Driver and control low-level input voltage | DIN, FORCEOFF, FORCEON, EN | | | | 0.8 | V |
| VI | Driver and control input voltage | DIN, FORCEOFF, FORCEON | | 0 | | 5.5 | V |
| VI | Receiver input voltage | | | -25 | | 25 | V |
| т. | Operating free-air temperature | | SN65C3221 | -40 | | 85 | °C |
| T_A | Operating nee-an temperature | SN75C3221 | 0 | | 70 | | |

(1) Test conditions are C1-C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2-C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.

⁽²⁾ All voltage values are with respect to network ground terminal GND.



6.3.1 Thermal Information

| | | SN65 | C3221 | SN75C3221 | | |
|-----------------------|--|-----------|------------|-----------|------------|------|
| | | DB (SSOP) | PW (TSSOP) | DB (SSOP) | PW (TSSOP) | |
| THERMAL M | IETRIC ¹ | 16 PINS | 16 PINS | 16 PINS | 16 PINS | UNIT |
| R _{θJA} | Junction-to-ambient thermal resistance | 82.0 | 110.9 | 105.8 | 108.0 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 45.7 | 41.7 | 51.9 | 41.1 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 44.4 | 57.2 | 57.6 | 51.4 | °C/W |
| Ψ _{JT} | Junction-to-top characterization parameter | 11.0 | 4.2 | 14.1 | 3.9 | °C/W |
| Ψ ЈВ | Junction-to-board characterization parameter | 43.8 | 56.6 | 56.8 | 50.9 | °C/W |

6.4 Electrical Characteristics

over recommended operating free-air temperature ranges of supply voltage and operating free-air temperature (unless otherwise noted)(2) (see Figure 9-1)

| | PARA | METER | TEST CONDITIONS | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|-----------------|-------------------------|-------------------------|---|-----|--------------------|-----|------|
| l _l | Input leakage current | FORCEOFF, FORCEON, EN | | | ±0.01 | ±1 | μA |
| | | Auto-powerdown disabled | No load, FORCEOFF and FORCEON at V _{CC} | | 0.3 | 1 | mA |
| | Supply current | Powered off | No load, FORCEOFF at GND | | 1 | 10 | |
| I _{CC} | (T _A = 25°C) | Auto-powerdown enabled | No load, FORCEOFF at V _{CC} , FORCEON at GND, All RIN are open or grounded | | 1 | 10 | μΑ |

All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.



6.5 Electrical Characteristics - Driver

over recommended ranges of supply voltage and operating free-air temperature range (unless otherwise noted)⁽³⁾ (see Figure 9-1)

| | PARAMETER | TE | ST CONDITIONS | 5 | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|------------------|---------------------------------------|---|--------------------------------|----------------------------------|-----|--------------------|-----|------|
| V _{OH} | High-level output voltage | DOUT at $R_L = 3 \text{ k}\Omega$ to GND, | DIN = GND | | 5 | 5.4 | | ٧ |
| V _{OL} | Low-level output voltage | DOUT at $R_L = 3 \text{ k}\Omega$ to GND, | DIN = V _{CC} | | -5 | -5.4 | | V |
| I _{IH} | High-level input current | $V_I = V_{CC}$ | | | | ±0.01 | ±1 | μA |
| I _{IL} | Low-level input current | V _I at GND | | | | ±0.01 | ±1 | μA |
| | Short-circuit output | V _{CC} = 3.6 V, | V _O = 0 V | | | ±35 | ±60 | mA |
| los | current ⁽²⁾ | V _{CC} = 5.5 V, | V _O = 0 V | | | ±35 | ±90 | |
| r _o | Output resistance | V _{CC} , V+, and V− = 0 V, | V _O = ±2 V | V _O = ±2 V | | 10M | | Ω |
| I _{off} | Output leakage current FORCEOFF = GND | V _O = ±12 V, | V _{CC} = 3 V to 3.6 V | | | ±25 | | |
| | | FURGEOFF = GND | V _O = ±10 V, | V _{CC} = 4.5 V to 5.5 V | | | ±25 | μA |

- All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. (1)
- Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.
- Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.

6.6 Switching Characteristics - Driver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(3) (see Figure 9-1)

| ı | PARAMETER | Т | TEST CONDITIONS | | | TYP ⁽¹⁾ | IAX | UNIT |
|------------------------------------|---|--|------------------------------------|----------------------------------|------|--------------------|-----|--------|
| Maximum data rate (see Figure 7-1) | | | C _L = 1000 pF | | 250 | | | |
| | | $R_L = 3 k\Omega$ | C _L = 250 pF, | V _{CC} = 3 V to 4.5 V | 1000 | | | kbit/s |
| | | | C _L = 1000 pF, | V _{CC} = 4.5 V to 5.5 V | 1000 | | | |
| t _{sk(p)} | Pulse skew ⁽²⁾ | C _L = 150 pF to 2500 pF | R_L = 3 kΩ to 7 kΩ, | See Figure 7-2 | | 100 | | ns |
| SR(tr) | Slew rate, transition region (see Figure 7-1) | V_{CC} = 3.3 V, R _L = 3 kΩ to 7 kΩ | C _L = 150 pF to 1000 pF | | 18 | | 150 | V/µs |

- All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.
- Pulse skew is defined as $|t_{PLH} t_{PHL}|$ of each channel of the same device.
- Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.

6.7 Electrical Characteristics - Receiver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)⁽²⁾ (see Figure 9-1)

| PARAMETER | | TEST CONDITIONS | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|-------------------|---|--------------------------------|-------------------------|-------------------------|-----|------|
| V _{OH} | High-level output voltage | I _{OH} = −1 mA | V _{CC} - 0.6 V | V _{CC} - 0.1 V | | V |
| V _{OL} | Low-level output voltage | I _{OL} = 1.6 mA | | | 0.4 | V |
| | Positive going input threshold voltage | V _{CC} = 3.3 V | | 1.6 | 2.4 | V |
| V _{IT+} | Positive-going input threshold voltage | V _{CC} = 5 V | | 1.9 | 2.4 | V |
| V | Negative-going input threshold voltage | V _{CC} = 3.3 V | 0.6 | 1.1 | | V |
| V _{IT} _ | Negative-going input tilleshold voltage | V _{CC} = 5 V | 0.8 | 1.4 | | V |
| V _{hys} | Input hysteresis (V _{IT+} - V _{IT-}) | | | 0.5 | | V |
| I _{off} | Output leakage current | FORCEOFF = 0 V | | ±0.05 | ±10 | μΑ |
| r _i | Input resistance | V _I = ±3 V to ±25 V | 3 | 5 | 7 | kΩ |

- All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. (2)



6.8 Switching Characteristics - Receiver

over recommended ranges of supply voltage and operating free-air temperature range (unless otherwise noted)(3)

| | PARAMETER | | MIN | TYP ⁽¹⁾ | MAX | UNIT | | | |
|--------------------|---|---|-----|--------------------|-------|------|-----|--|----|
| t _{PLH} | nign-ievei output | C _L = 150 pF, | | See Figure | ∍ 7-3 | | 150 | | ns |
| t _{PHL} | Propagation delay time, high- to low-level output | C _L = 150 pF, | | See Figure 7-3 | | 150 | | | ns |
| t _{en} | Output enable time | $C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega,$ | | , See Figure 7-4 | | | 200 | | ns |
| t _{dis} | Output disable time | $C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega,$ | | Ω, See Figure 7- | | | 200 | | ns |
| t _{sk(p)} | Pulse skew ⁽²⁾ | See Figure 7-3 | | | | | 50 | | ns |

- (1) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.
- (2) Pulse skew is defined as |t_{PLH} t_{PHL}| of each channel of the same device.
- (3) Test conditions are C1-C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2-C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.

6.9 Electrical Characteristics - Auto-Powerdown

over recommended ranges of supply voltage and operating free-air temperature range (unless otherwise noted) (see Figure 7-5)

| | PARAMETER | TEST CO | NDITIONS | MIN | MAX | UNIT |
|-------------------------|--|---|----------------------------|----------------------|-----|------|
| V _{T+(valid)} | Receiver input threshold for INVALID high-level output voltage | FORCEON = GND, | FORCEOFF = V _{CC} | | 2.7 | V |
| V _{T-(valid)} | Receiver input threshold for INVALID high-level output voltage | FORCEON = GND, | FORCEOFF = V _{CC} | -2.7 | | V |
| V _{T(invalid)} | Receiver input threshold for INVALID low-level output voltage | FORCEON = GND, | FORCEOFF = V _{CC} | -0.3 | 0.3 | V |
| V _{OH} | INVALID high-level output voltage | I _{OH} = -1 mA, FORCE FORCEOFF = V _{CC} | EON = GND, | V _{CC} -0.6 | | V |
| V _{OL} | INVALID low-level output voltage | I _{OL} = 1.6 mA, FORCE FORCEOFF = V _{CC} | | 0.4 | V | |

6.10 Switching Characteristics - Auto-Powerdown

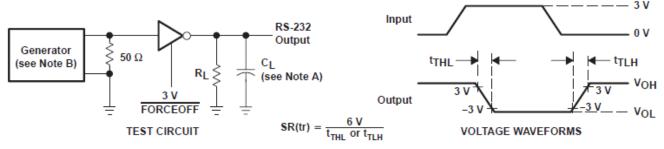
over operating free-air temperature range (unless otherwise noted) (see Figure 7-5)

| | PARAMETER | MIN TYP ⁽¹⁾ MAX | UNIT |
|----------------------|---|----------------------------|------|
| t _{valid} | Propagation delay time, low- to high-level output | 1 | μs |
| t _{invalid} | Propagation delay time, high- to low-level output | 30 | μs |
| t _{en} | Supply enable time | 100 | μs |

(1) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.



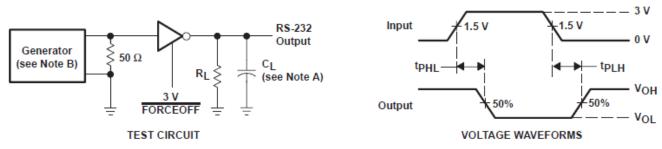
7 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_{O} = 50 Ω , 50% duty cycle, $t_{r} \le 10$ ns, $t_{f} \le 10$ ns.

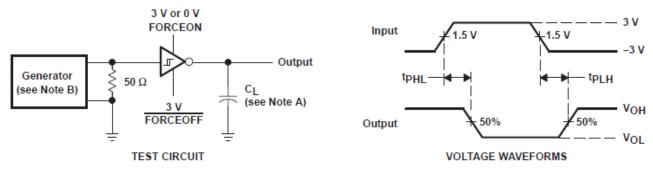
Figure 7-1. Driver Slew Rate



NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 7-2. Driver Pulse Skew

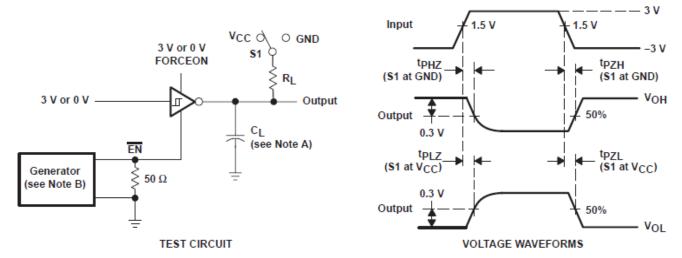


NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_O = 50 \ \Omega$, 50% duty cycle, $t_\Gamma \le 10 \ ns$.

Figure 7-3. Receiver Propagation Delay Times



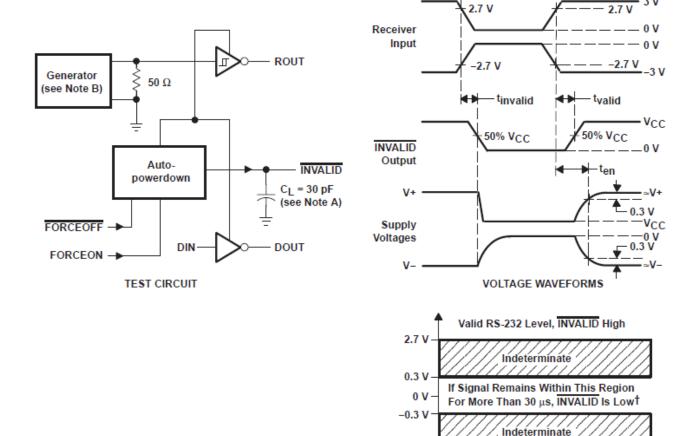


NOTES: A. C_L includes probe and jig capacitance.

- B. The pulse generator has the following characteristics: $Z_O = 50 \ \Omega$, 50% duty cycle, $t_\Gamma \le 10 \ ns$, $t_f \le 10 \ ns$.
- C. tpLZ and tpHZ are the same as tdis.
- D. tpzL and tpzH are the same as ten.

Figure 7-4. Receiver Enable and Disable Times





† Auto-powerdown disables drivers and reduces supply current to 1 μA.

Valid RS-232 Level, INVALID High

NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 5 kbit/s, Z_O = 50 Ω , 50% duty cycle, $t_f \le$ 10 ns, $t_f \le$ 10 ns.

-2.7 V

Figure 7-5. INVALID Propagation Delay Times and Driver Enabling Time



8 Detailed Description

8.1 Device Functional Modes

Table 8-1. Each Driver⁽¹⁾

| | INP | OUTPUT | | | |
|-----|---------|----------|---------------------------|------|-----------------------------|
| DIN | FORCEON | FORCEOFF | VALID RIN RS-232 LEVEL | DOUT | DRIVER STATUS |
| Х | Х | L | Х | Z | Powered off |
| L | Н | Н | X | Н | Normal operation with auto- |
| Н | Н | Н | X | L | powerdown disabled |
| L | L | Н | Yes | Н | Normal operation with auto- |
| Н | L | Н | Yes | L | powerdown enabled |
| L | L | Н | No | Z | Powered off by auto- |
| Н | L | Н | No | Z | powerdown feature |

(1) H = high level, L = low level, X = irrelevant, Z = high impedance

Table 8-2. Each Receiver(1)

| | OUTPUT | | | | |
|------|--------|----|------|--|--|
| RIN | RIN EN | | ROUT | | |
| L | L | X | Н | | |
| Н | L | X | L | | |
| X | Н | X | Z | | |
| Open | L | No | Н | | |

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = disconnected input or connected driver off.

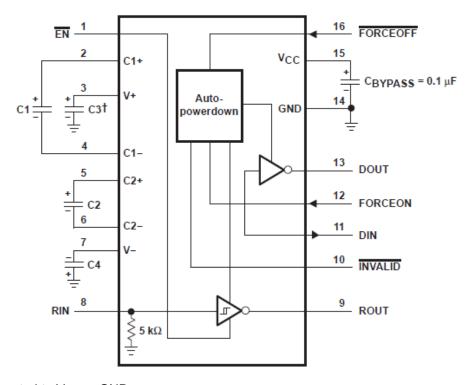


9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information



 \dagger C3 can be connected to $V_{CC}\, or\, GND$

Resistor values shown are nominal.

Figure 9-1. Typical Operating Circuit and Capacitor Values

Table 9-1. V_{CC} vs Capacitator Values

| V _{CC} | C1 | C2, C3, and C4 |
|-----------------|----------|----------------|
| 3.3 V ± 0.3 V | 0.1 μF | 0.1 μF |
| 5 V ± 0.5 V | 0.047 µF | 0.33 μF |
| 3 V to 5.5 V | 0.1 μF | 0.47 µF |



10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

10.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

| Orderable part number | Status | Material type | Package Pins | Package qty Carrier | RoHS | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking |
|-----------------------|----------|---------------|-----------------|-----------------------|------|-------------------------------|----------------------------|--------------|--------------|
| | (') | (2) | | | (0) | (4) | (5) | | (0) |
| SN65C3221DB | Obsolete | Production | SSOP (DB) 16 | - | - | Call TI | Call TI | -40 to 85 | CB3221 |
| SN65C3221DBR | Obsolete | Production | SSOP (DB) 16 | - | - | Call TI | Call TI | -40 to 85 | CB3221 |
| SN65C3221PWR | Active | Production | TSSOP (PW) 16 | 2000 LARGE T&R | Yes | NIPDAU SN | Level-1-260C-UNLIM | -40 to 85 | CB3221 |
| SN65C3221PWR.A | Active | Production | TSSOP (PW) 16 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CB3221 |
| SN65C3221PWRG4 | Active | Production | TSSOP (PW) 16 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CB3221 |
| SN75C3221DBR | Active | Production | SSOP (DB) 16 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | CA3221 |
| SN75C3221DBR.A | Active | Production | SSOP (DB) 16 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | CA3221 |
| SN75C3221DW | Preview | Production | SOIC (DW) 16 | 40 TUBE | - | Call TI | Call TI | 0 to 70 | |
| SN75C3221PWR | Active | Production | TSSOP (PW) 16 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | CA3221 |
| SN75C3221PWR.A | Active | Production | TSSOP (PW) 16 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | CA3221 |

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

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and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN65C3221:

Automotive: SN65C3221-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| SN65C3221PWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| SN65C3221PWRG4 | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| SN65C3221PWRG4 | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| SN75C3221DBR | SSOP | DB | 16 | 2000 | 330.0 | 16.4 | 8.35 | 6.6 | 2.4 | 12.0 | 16.0 | Q1 |
| SN75C3221PWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |



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*All dimensions are nominal

| 7th difficilisions are norminal | | | | | | | |
|---------------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| SN65C3221PWR | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| SN65C3221PWRG4 | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| SN65C3221PWRG4 | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| SN75C3221DBR | SSOP | DB | 16 | 2000 | 353.0 | 353.0 | 32.0 |
| SN75C3221PWR | TSSOP | PW | 16 | 2000 | 353.0 | 353.0 | 32.0 |





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-150.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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